December 2007

74VHCT00A
Quad 2-Input NAND Gate

Features

- High speed: t_{PD} = 5.0ns (Typ.) at T_A = 25°C
- High noise immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power down protection is provided on all inputs and outputs
- Low noise: V_{OLP} = 0.8V (Max.)
- Low power dissipation: I_{CC} = 2A (Max.) at T_A = 25°C
- Pin and function compatible with 74HCT00

General Description

The VHCT00A is an advanced high-speed CMOS 2-Input NAND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages, including buffer output, which provide high noise immunity and stable output.

Protection circuits ensure that 0V to 7V can be applied to the input pins without regard to the supply voltage and to the output pins with V_{CC} = 0V. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 3V to 5V systems and two supply systems such as battery backup.

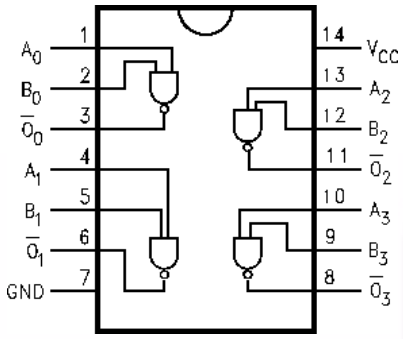
Ordering Information

Order Number	Package Number	Package Description
74VHCT00AM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHCT00ASJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT00AMTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

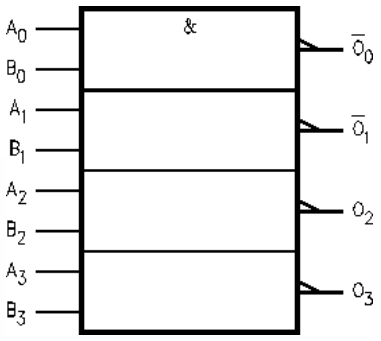
Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagram



Logic Symbol



Pin Description

Pin Names	Description
A_n, B_n	Inputs
$\overline{O}_n$	Outputs

Truth Table

A	B	$\overline{O}$
L	L	H
L	H	H
H	L	H
H	H	L

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V_{CC}	Supply Voltage	–0.5V to +7.0V
V_{IN}	DC Input Voltage	–0.5V to +7.0V
V_{OUT}	DC Output Voltage	
	Note 1	–0.5V to V_{CC} + 0.5V
	Note 2	–0.5V to 7.0V
I_{IK}	Input Diode Current	–20mA
I_{OK}	Output Diode Current(3)	±20mA
I_{OUT}	DC Output Current	±25mA
I_{CC}	DC V_{CC} / GND Current	±50mA
T_{STG}	Storage Temperature	–65°C to +150°C
T_L	Lead Temperature (Soldering, 10 seconds)	260°C

Recommended Operating Conditions(4)

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V_{CC}	Supply Voltage	4.5V to +5.5V
V_{IN}	Input Voltage	0V to +5.5V
V_{OUT}	Output Voltage	
	Note 1	0V to V_{CC}
	Note 2	0V to 5.5V
T_{OPR}	Operating Temperature	–40°C to +85°C
t_r, t_f	Input Rise and Fall Time, V_{CC} = 5.0V ±0.5V	0ns/V ~ 20ns/V

Notes:

1. HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.
2. V_{CC} = 0V.
3. V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).
4. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	Conditions		T_A = 25°C			T_A = –40°C to +85°C		Units
					Min.	Typ.	Max.	Min.	Max.	
V_{IH}	HIGH Level Input Voltage	4.5			2.0			2.0		V
		5.5			2.0			2.0		
V_{IL}	LOW Level Input Voltage	4.5					0.8		0.8	V
		5.5					0.8		0.8	
V_{OH}	HIGH Level Output Voltage	4.5	V_{IN} = V_{IH} or V_{IL}	I_{OH} = –50μA	4.40	4.50		4.40		V
				I_{OH} = –8mA	3.94			3.80		
V_{OL}	LOW Level Output Voltage	4.5	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA		0.0	0.1		0.1	V
				I_{OL} = 8mA			0.36		0.44	
I_{IN}	Input Leakage Current	0 – 5.5	V_{IN} = 5.5V or GND				±0.1		±1.0	μA
I_{CC}	Quiescent Supply Current	5.5	V_{IN} = V_{CC} or GND				2.0		20.0	μA
I_{CCT}	Maximum I_{CC} / Input	5.5	V_{IN} = 3.4V, Other Inputs = V_{CC} or GND				1.35		1.50	mA
I_{OFF}	Output Leakage Current (Power Down State)	0.0	V_{OUT} = 5.5V				0.5		5.0	μA

Noise Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C		Units
				Typ.	Limit	
V_{OLP}[5]	Quiet Output Maximum Dynamic V_{OL}	C_L = 50pF	5.0	0.4	0.8	V
V_{OLV}[5]	Quiet Output Minimum Dynamic V_{OL}	C_L = 50pF	5.0	–0.4	–0.8	V
V_{IHD}[5]	Minimum HIGH Level Dynamic Input Voltage	C_L = 50pF	5.0		2.0	V
V_{ILD}[5]	Maximum LOW Level Dynamic Input Voltage	C_L = 50pF	5.0		0.8	V

Note:

5. Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	Conditions	T_A = 25°C			T_A = –40°C to +85°C		Units
				Min.	Typ.	Max.	Min.	Max.	
t_{PLH}, t_{PHL}	Propagation Delay	5.0 ± 0.5	C_L = 15pF		5.0	6.9	1.0	8.0	ns
			C_L = 50pF		5.5	7.9	1.0	9.0	
C_{IN}	Input Capacitance		V_{CC} = Open		4	10		10	pF
C_{PD}	Power Dissipation Capacitance		[6]		17				pF

Note:

6. C_{PD} is defined as the value of the internal equivalent capacitance, which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (Opr.) = C_{PD} • V_{CC} • f_{IN} + I_{CC} / 4 (per gate)

Physical Dimensions

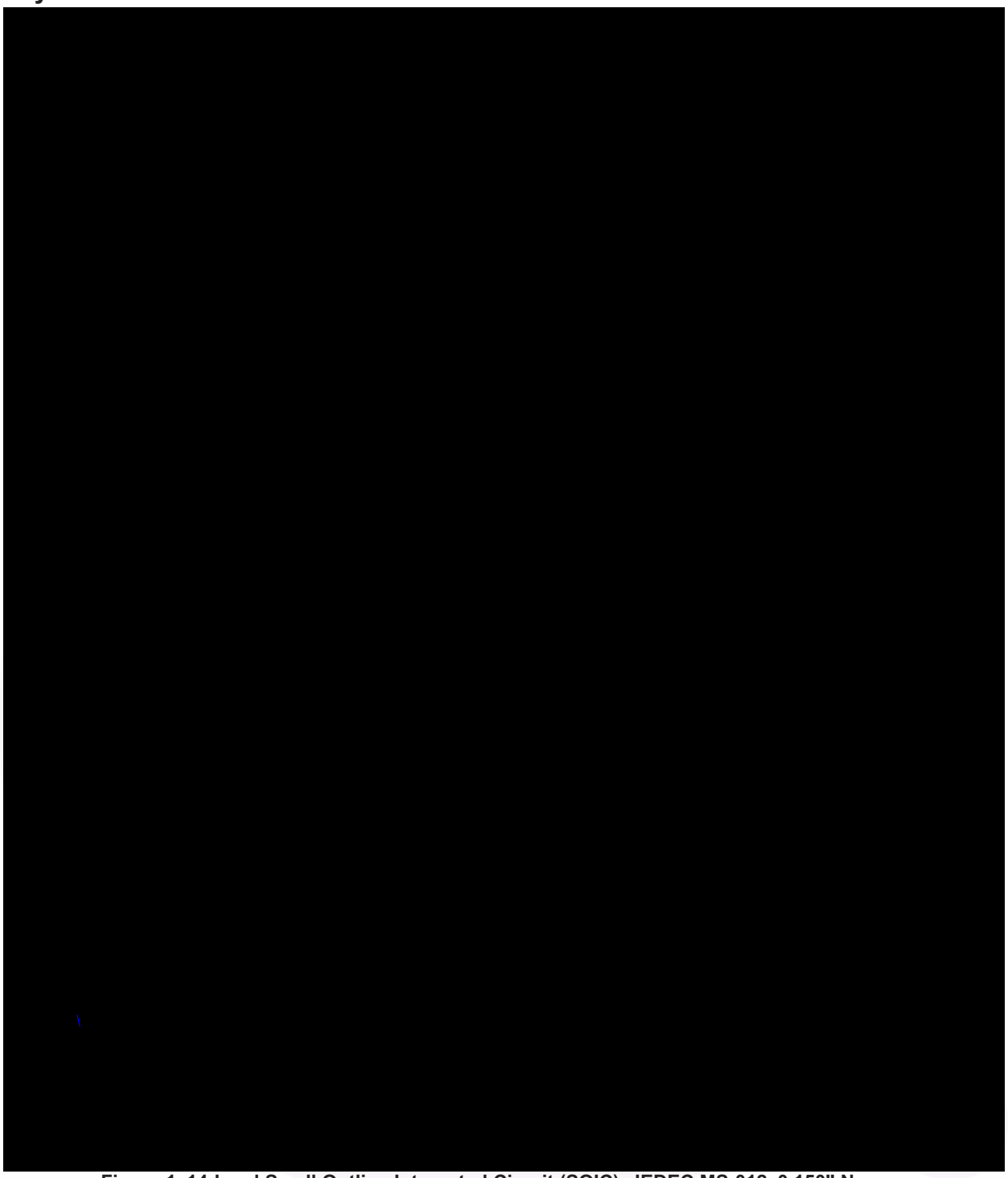


Figure 1. 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow

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Physical Dimensions (Continued)

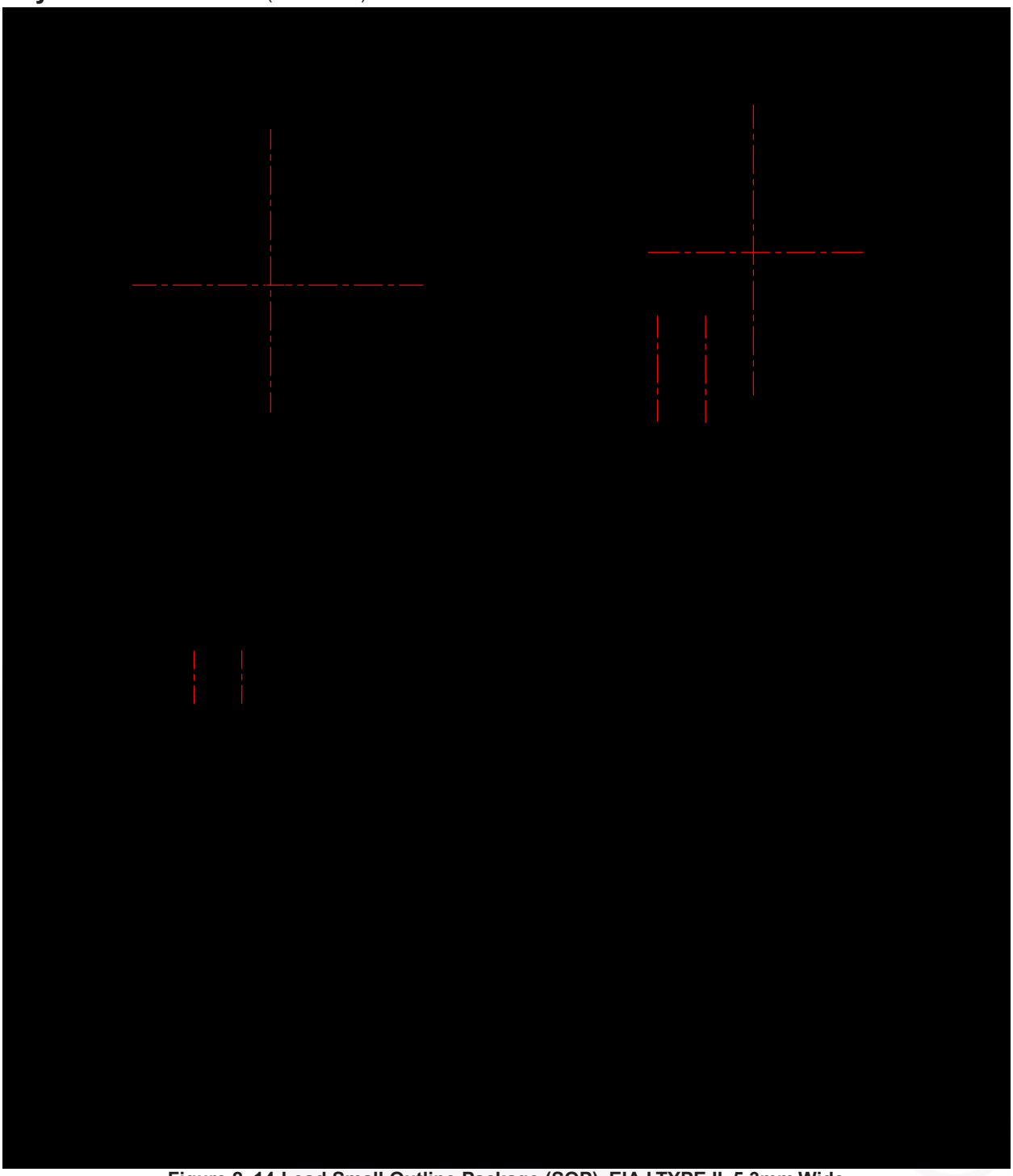

Figure 2. 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

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Physical Dimensions (Continued)

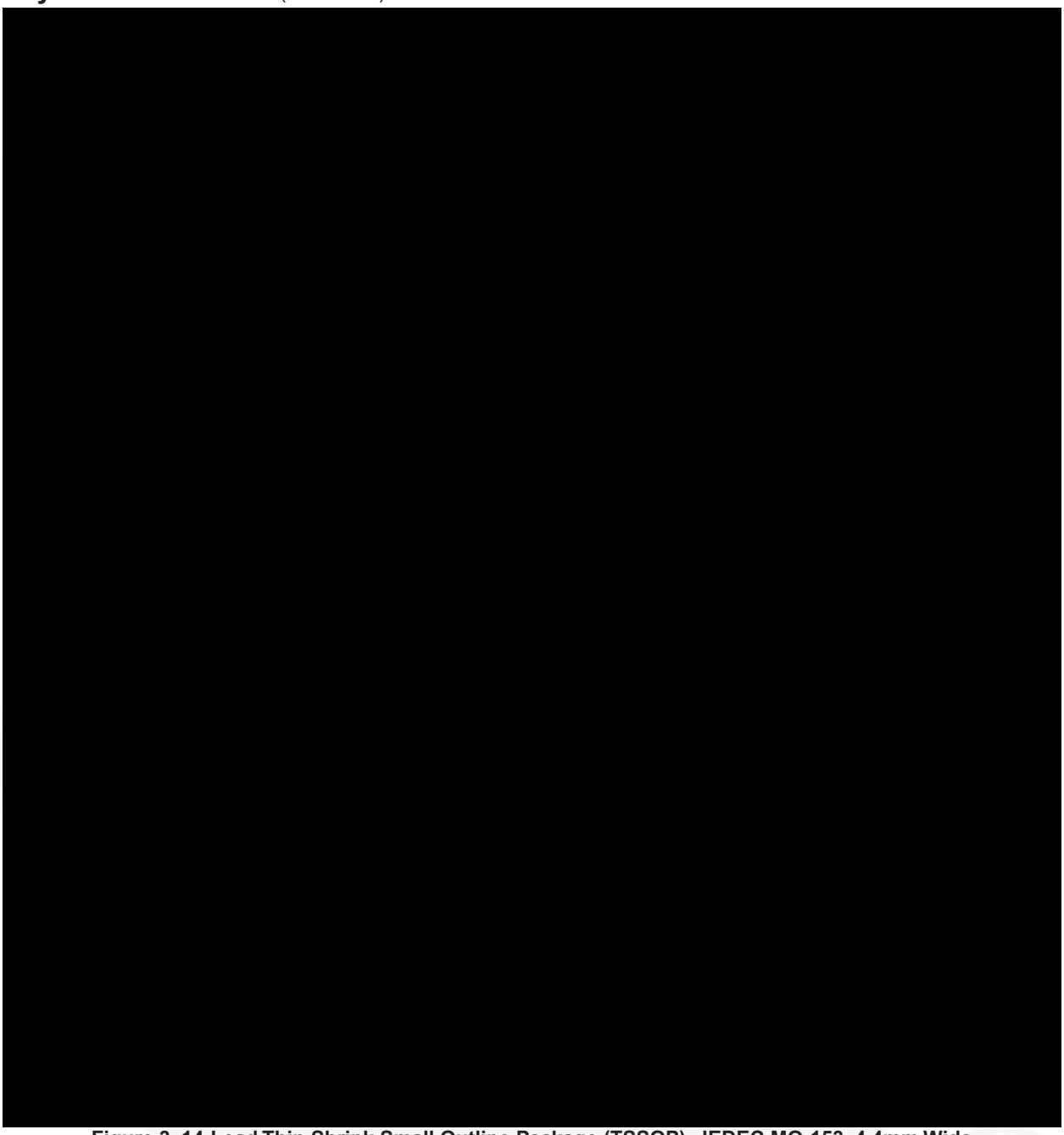

Figure 3. 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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